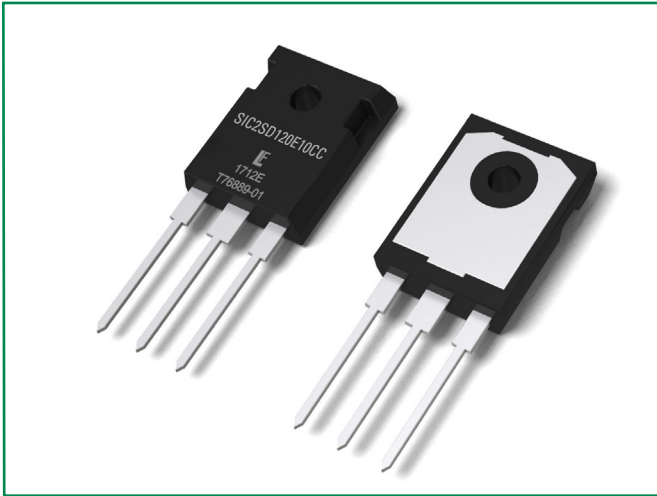


**LSIC2SD120E10CC**



**Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. This diode series is ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

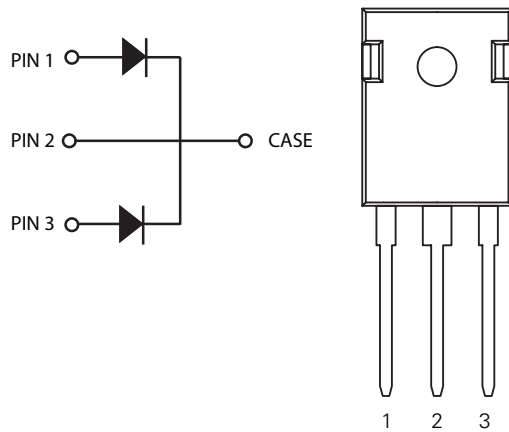
**Features**

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

**Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

**Circuit Diagram TO-247-3L**



**Environmental**

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

**Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	-	1200	V
DC Blocking Voltage	$V_R$	$T_J = 25\text{ °C}$	1200	V
Continuous Forward Current (Per Leg/Component)	$I_F$	$T_C = 25\text{ °C}$	17.5/35	A
		$T_C = 135\text{ °C}$	8.5/17	
		$T_C = 158\text{ °C}$	5/10	
Non-Repetitive Forward Surge Current (Per Leg)	$I_{FSM}$	$T_C = 25\text{ °C}, T_P = 10\text{ ms}, \text{Half sine pulse}$	40	A
Power Dissipation (Per Leg/Component)	$P_{Tot}$	$T_C = 25\text{ °C}$	100/200	W
		$T_C = 110\text{ °C}$	43/86	
Operating Junction Temperature	$T_J$	-	-55 to 175	°C
Storage Temperature	$T_{STG}$	-	-55 to 150	°C
Soldering Temperature	$T_{sold}$	-	260	°C

**Electrical Characteristics (Per Leg)**

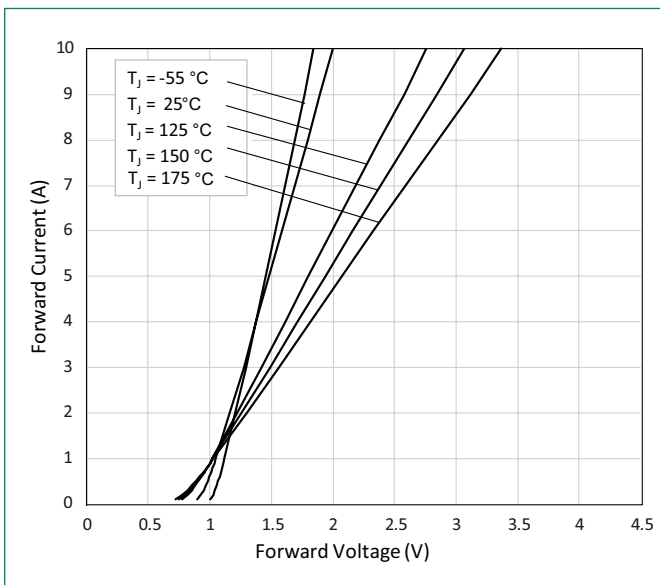
Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F = 5 \text{ A}, T_J = 25 \text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 5 \text{ A}, T_J = 175 \text{ }^\circ\text{C}$	-	2.1		
Reverse Current	$I_R$	$V_R = 1200 \text{ V}, T_J = 25 \text{ }^\circ\text{C}$	-	<1	100	$\mu\text{A}$
		$V_R = 1200 \text{ V}, T_J = 175 \text{ }^\circ\text{C}$	-	5		
Total Capacitance	C	$V_R = 1 \text{ V}, f = 1 \text{ MHz}$	-	310		pF
		$V_R = 400 \text{ V}, f = 1 \text{ MHz}$	-	29		
		$V_R = 800 \text{ V}, f = 1 \text{ MHz}$	-	21		
Total Capacitive Charge	$Q_C$	$V_R = 800 \text{ V}, Q_C = \int_0^{V_R} C(V) dV$	-	30	-	nC

Footnote:  $T_J = +25 \text{ }^\circ\text{C}$  unless otherwise specified

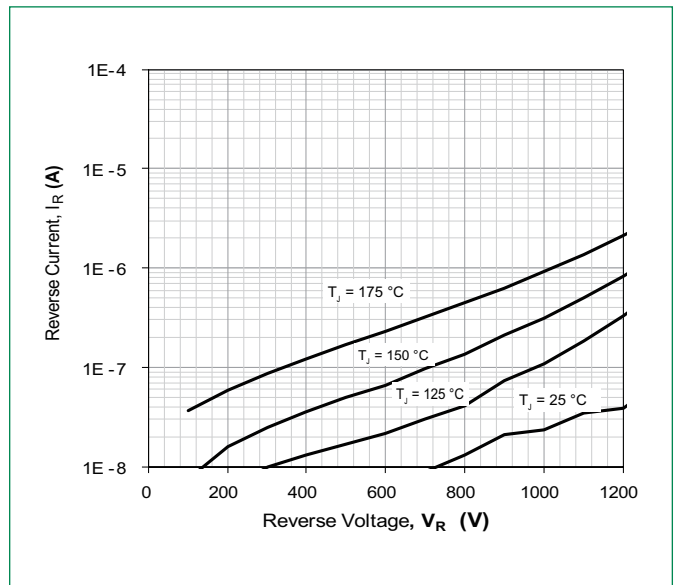
**Thermal Characteristics**

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance (Per Leg/Component)	$R_{\theta JC}$	-	-	0.75 / 1.5	-	$^\circ\text{C/W}$

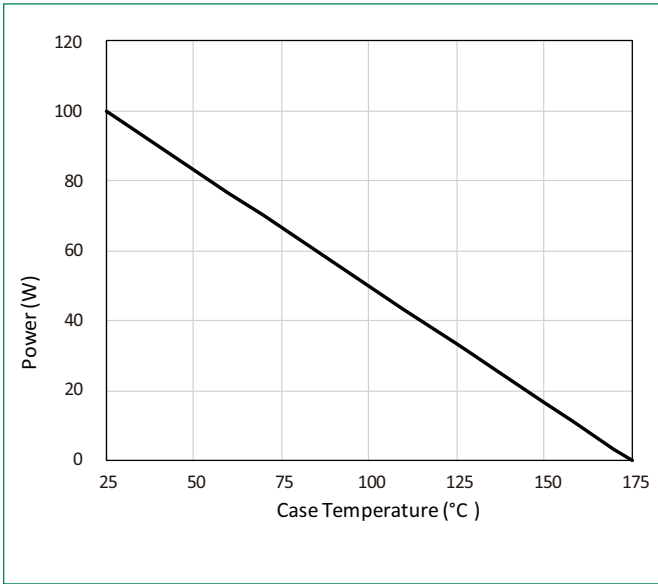
**Figure 1: Typical Forward Characteristics (Per Leg)**



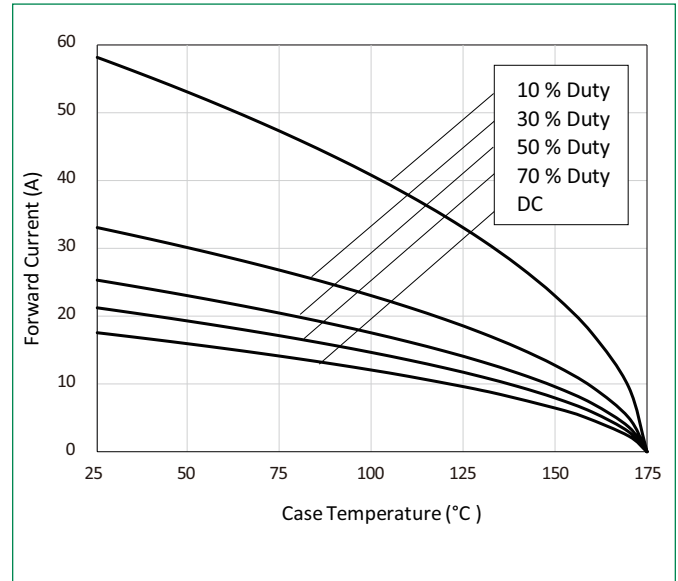
**Figure 2: Typical Reverse Characteristics (Per Leg)**



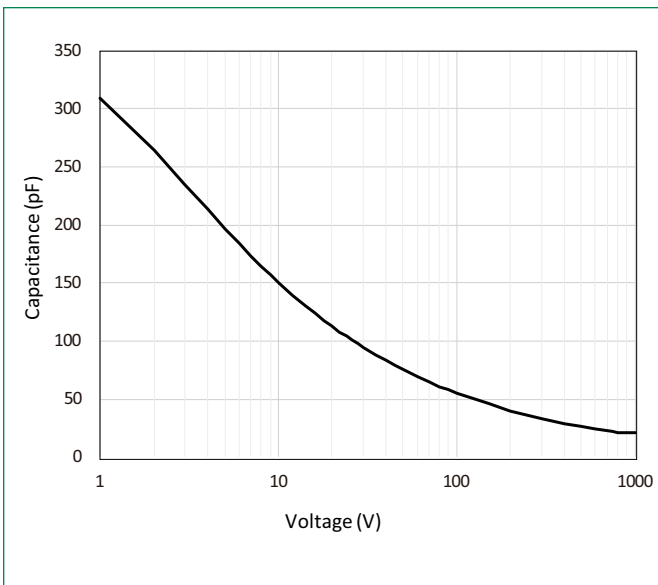
**Figure 3: Power Derating (Per Leg)**



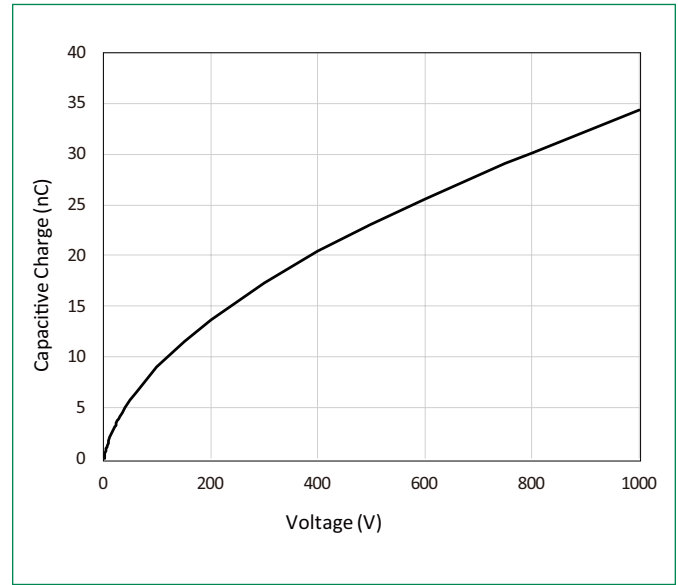
**Figure 4: Current Derating (Per Leg)**



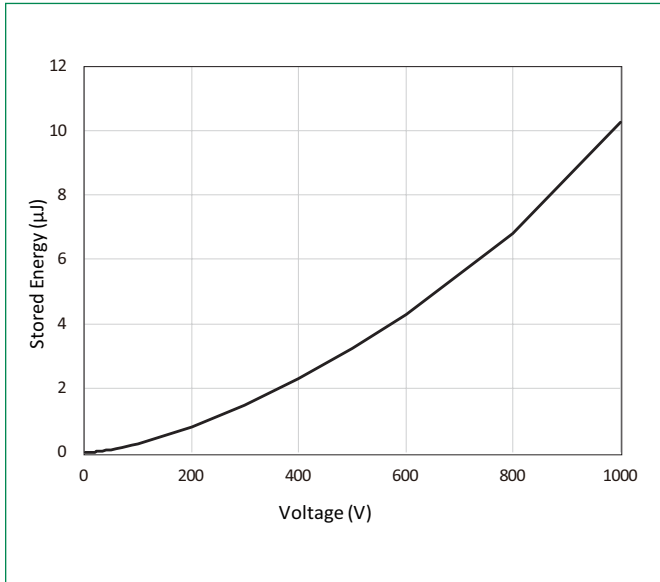
**Figure 5: Capacitance vs. Reverse Voltage (Per Leg)**



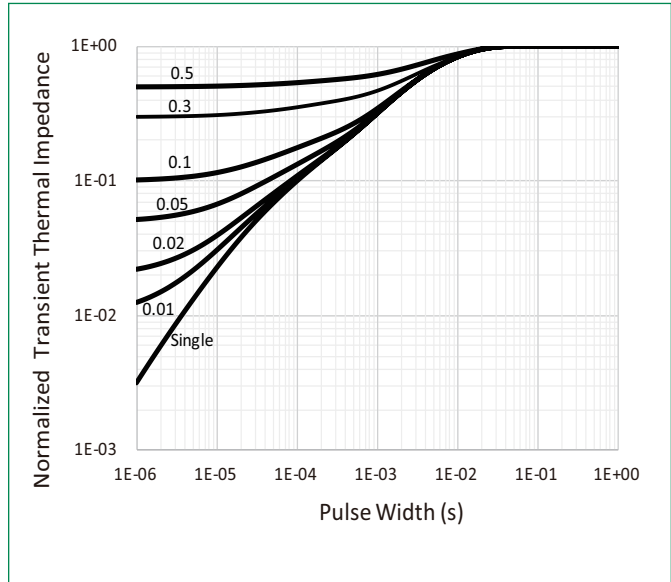
**Figure 6: Capacitive Charge vs. Reverse Voltage (Per Leg)**



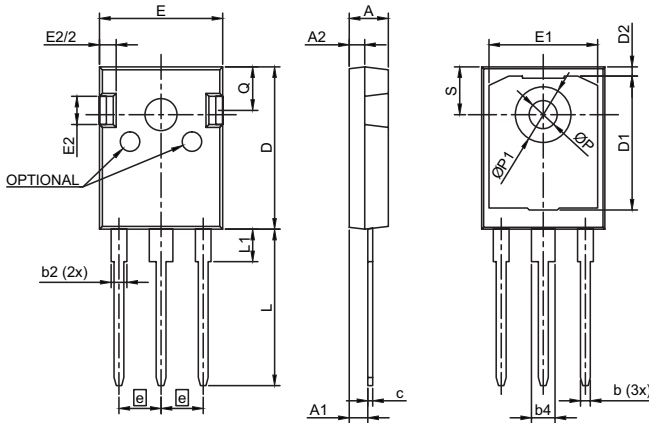
**Figure 7: Stored Energy vs. Reverse Voltage (Per Leg)**



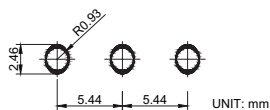
**Figure 8: Transient Thermal Impedance (Per Component)**



**Package Dimensions TO-247-3L**



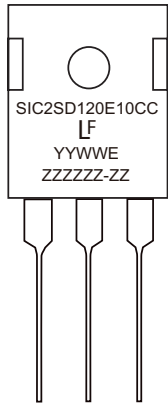
**Recommended Hole Pattern Layout**



- Notes:
1. Dimensions are in millimeters
  2. Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These measured at the outermost extreme of plastic body.
  3.  $\phi P$  to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 0.154"

Symbol	Millimeters		
	Min	Nom	Max
A	4.80	5.03	5.20
A1	2.25	2.38	2.54
A2	1.85	1.98	2.11
b	0.99	-	1.40
b2	1.65	-	2.39
b4	2.59	-	3.43
c	0.38	0.64	0.89
D	20.80	20.96	21.34
D1	13.50	-	-
D2	0.51	1.19	1.35
e	5.44 BSC		
E	15.75	15.90	16.13
E1	13.06	14.02	14.15
E2	4.19	4.32	4.83
L	19.81	20.19	20.57
L1	3.81	4.19	4.45
$\phi P$	3.55	3.61	3.66
$\phi P1$	7.06	7.19	7.32
Q	5.49	5.61	6.20
S	6.05	6.17	6.30

### Part Numbering and Marking System

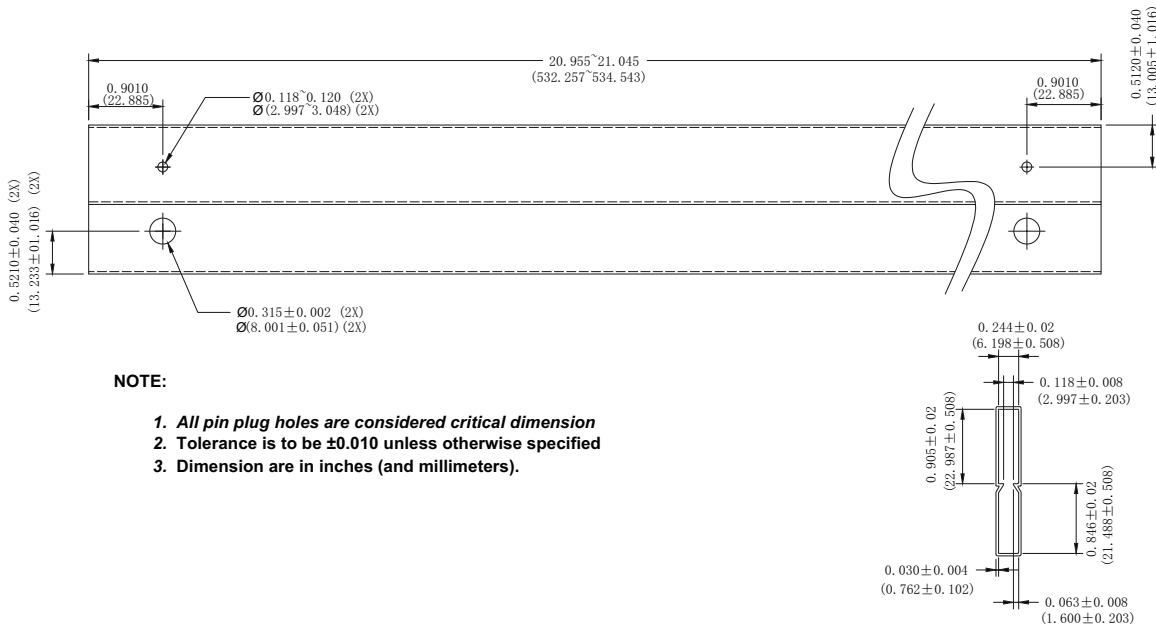


- SIC = SiC
- 2 = Gen2
- SD = Schottky Diode
- 120 = Voltage Rating (1200 V)
- E = TO-247-3L
- 10 = Current Rating (10 A)
- CC = Common Cathode
- YY = Year
- WW = Week
- E = Special Code
- ZZZZZZ-ZZ = Lot Number

### Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120E10CC	SIC2SD120E10CC	Tube (30pcs)	450

### Packing Specification TO-247-3L



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